



GaAs PHEMT MMIC HIGH IP3 LOW NOISE AMPLIFIER, 1.3 - 2.9 GHz

Typical Applications

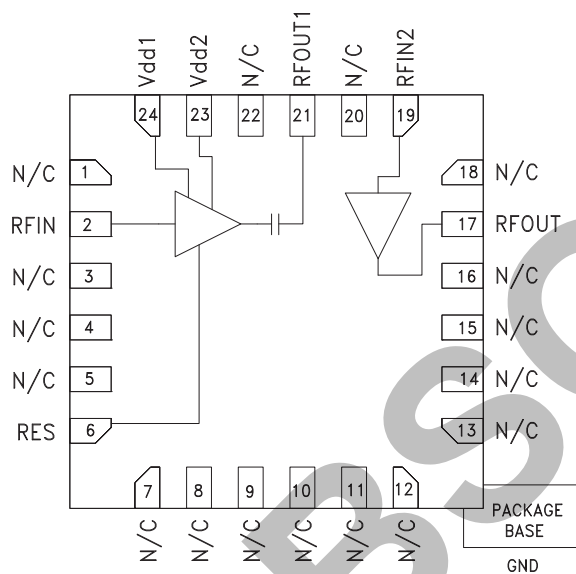
The HMC719LP4(E) is ideal for:

- Cellular/3G and LTE/WiMAX/4G
- BTS & Infrastructure
- Repeaters and Femtocells
- Access Points
- Test Equipment & Military

Features

- Noise Figure: 1.0 dB
- Gain: 34 dB
- Output IP3: +39 dBm
- Single Supply: +3V to +5V
- 50 Ohm Matched Input/Output
- 24 Lead 4x4 mm SMT Package: 16 mm²

Functional Diagram



General Description

The HMC719LP4(E) is a GaAs PHEMT MMIC Low Noise Amplifier that is ideal for Cellular/3G and LTE/WiMAX/4G basestation front-end receivers operating between 1.3 and 2.9 GHz. The amplifier has been optimized to provide 1.0 dB noise figure, 34 dB gain and +39 dBm output IP3 from a single supply of +5V. Input and output return losses are excellent and the LNA requires minimal external matching and bias decoupling components. The HMC719LP4(E) shares the same package and pinout with the HMC718LP3(E) 600 - 1400 MHz LNA. The HMC719LP4(E) can be biased with +3V to +5V and features an externally adjustable supply current which allows the designer to tailor the linearity performance of the LNA for each application.

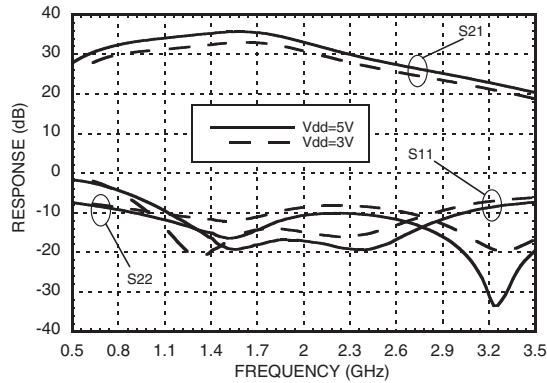
Electrical Specifications, $T_A = +25^\circ\text{C}$, $R_{bias} = 1.5k\ \text{Ohms}^*$

Parameter	Vdd = +3V			Vdd = +5V			Vdd = +3V			Vdd = +5V			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	1.3 - 2.2			2.2 - 2.9			1.3 - 2.2			2.2 - 2.9			GHz
Gain	27	32		22	26.5		29	35		24	28		dB
Gain Variation Over Temperature		0.02			0.02			0.02			0.02		dB/°C
Noise Figure		1.0	1.3		1.3	1.6		0.95	1.2		1.25	1.6	dB
Input Return Loss		16			13.5			17.5			16.5		dB
Output Return Loss		10.5			9.5			13.5			11.5		dB
Output Power for 1 dB Compression (P1dB)	12.5	15.5		12.5	15.5		18	21.5		18	21.5		dBm
Saturated Output Power (Psat)		18			18.5			23			23		dBm
Output Third Order Intercept (IP3)		32			31			39			39		dBm
Total Supply Current (Idd)		187	220		187	220		272	315		272	315	mA

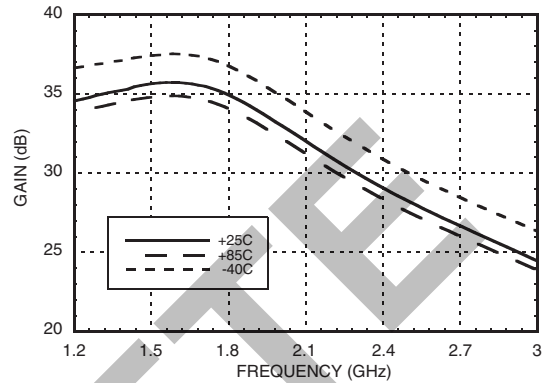
* Rbias resistor sets current, see application circuit herein, Vdd = Vdd1 = Vdd2



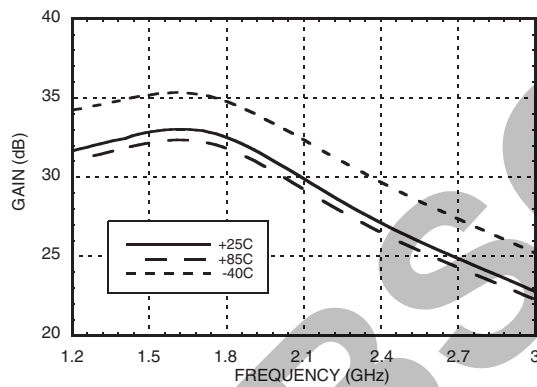
Broadband Gain & Return Loss [1] [2]



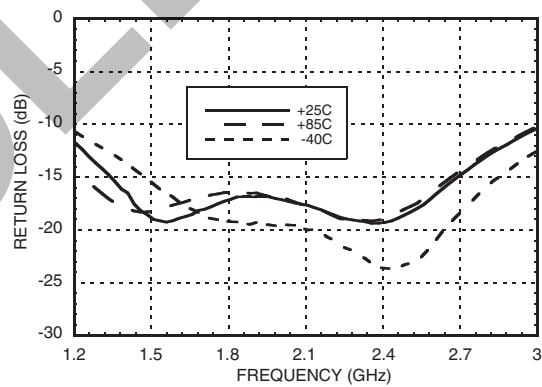
Gain vs. Temperature [1]



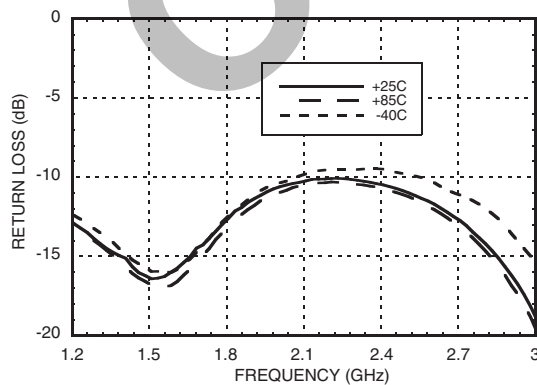
Gain vs. Temperature [2]



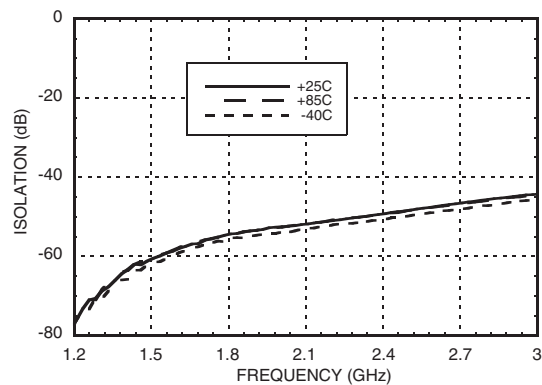
Input Return Loss vs. Temperature [1]



Output Return Loss vs. Temperature [1]



Reverse Isolation vs. Temperature [1]



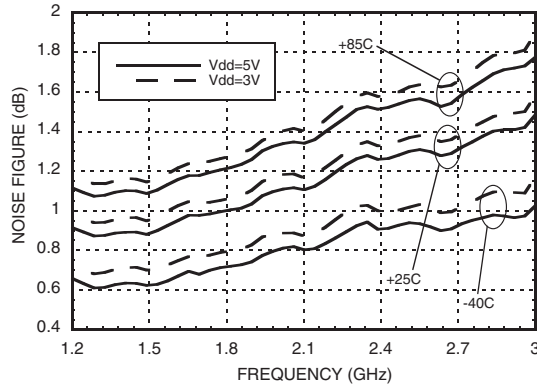
[1] Vdd = 5V, Rbias = 1.5K [2] Vdd = 3V, Rbias = 1.5K

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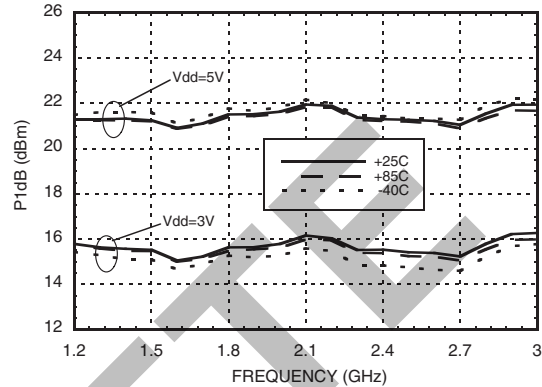
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



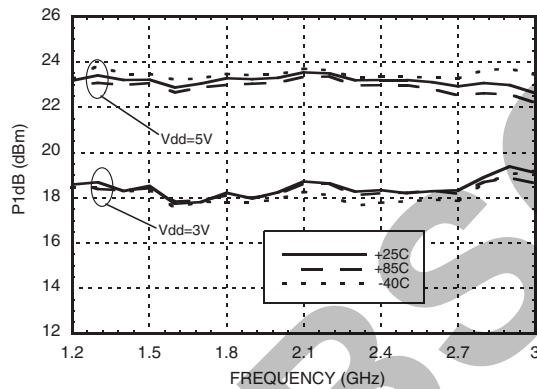
Noise Figure vs. Temperature [1] [2]



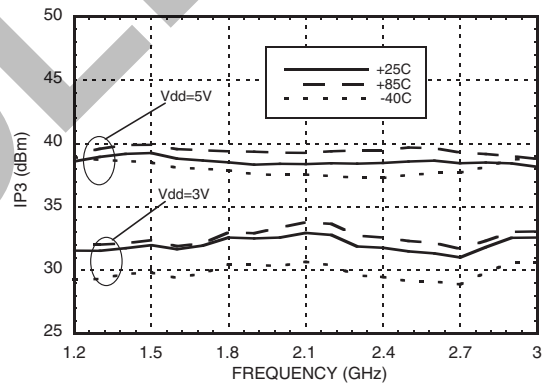
P1dB vs. Temperature [1] [2]



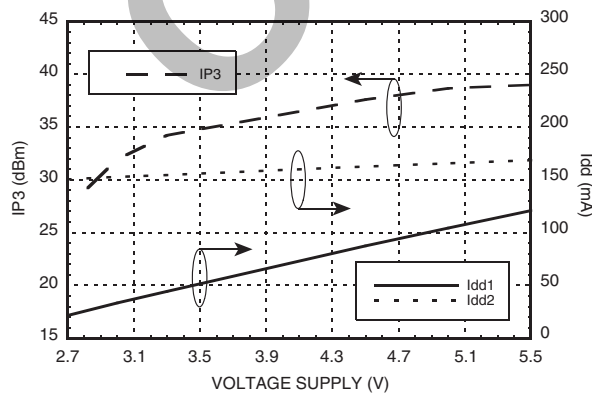
Psat vs. Temperature [1] [2]



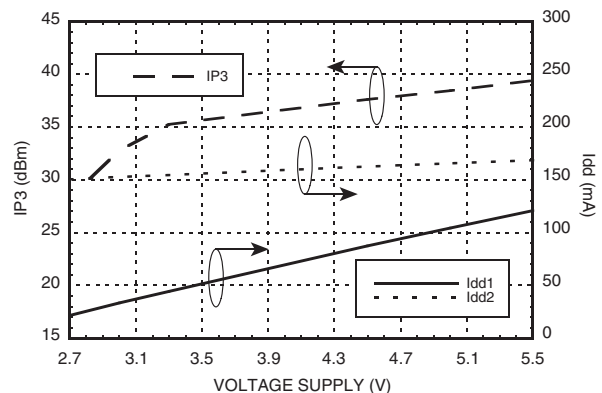
Output IP3 vs. Temperature [1] [2]



Output IP3 and Idd vs. Supply Voltage @ 1700 MHz [3]



Output IP3 and Idd vs. Supply Voltage @ 2200 MHz [3]



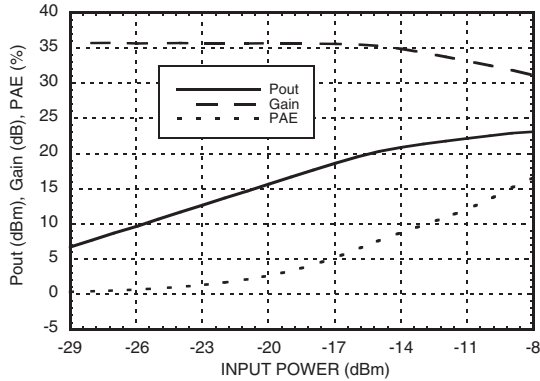
[1] Vdd = 5V, Rbias = 1.5K [2] Vdd = 3V, Rbias = 1.5K [3] Rbias = 1.5K

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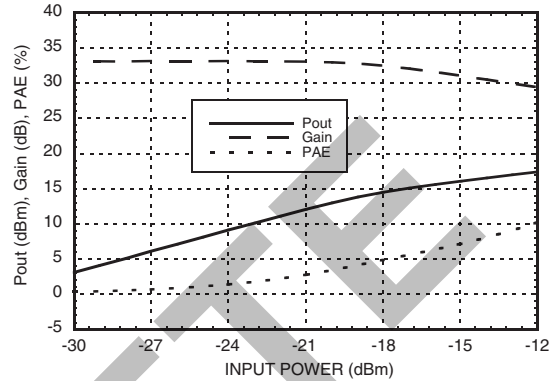
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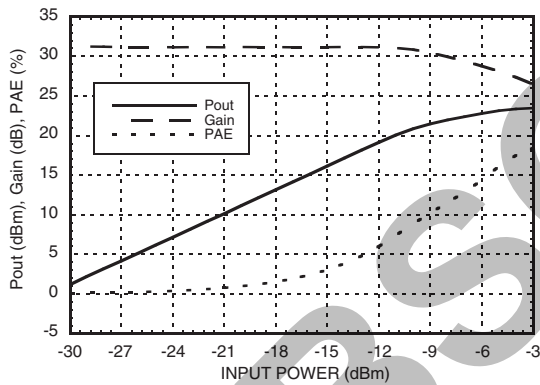
Power Compression @ 1700 MHz [1]



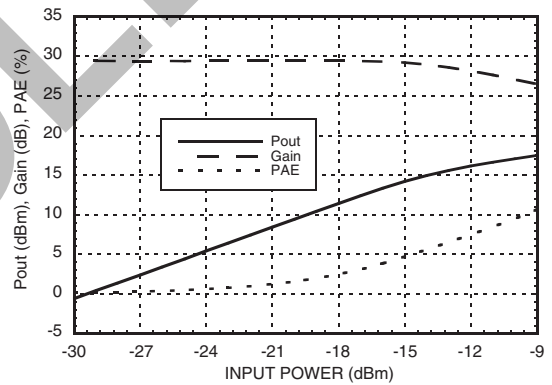
Power Compression @ 1700 MHz [2]



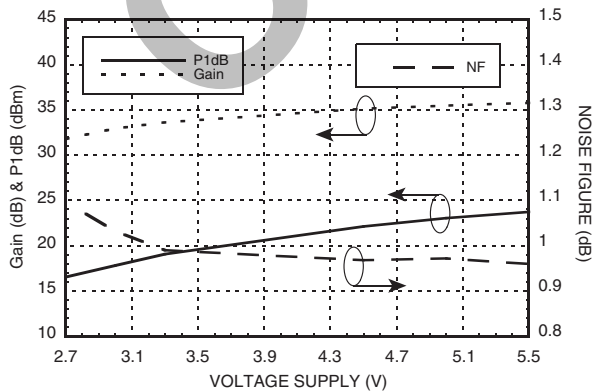
Power Compression @ 2200 MHz [1]



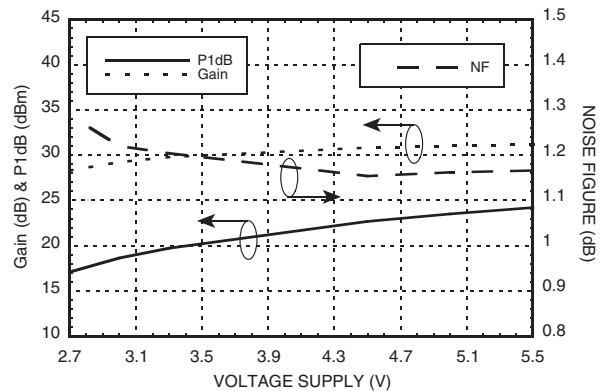
Power Compression @ 2200 MHz [2]



Gain, Power & Noise Figure vs. Supply Voltage @ 1700 MHz [3]



Gain, Power & Noise Figure vs. Supply Voltage @ 2200 MHz [3]



[1] Vdd = 5V, Rbias = 1.5K [2] Vdd = 3V, Rbias = 1.5K [3] Rbias = 1.5K

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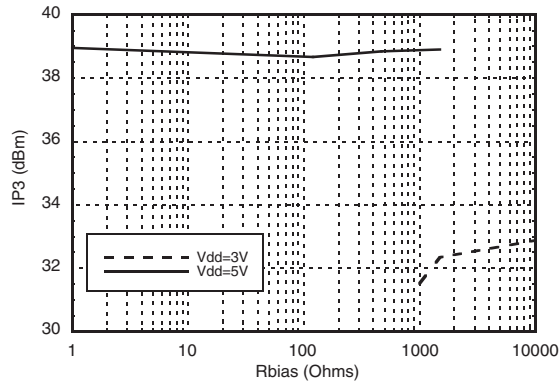
HMC719LP4 / 719LP4E

**GaAs PHEMT MMIC HIGH IP3
LOW NOISE AMPLIFIER, 1.3 - 2.9 GHz**

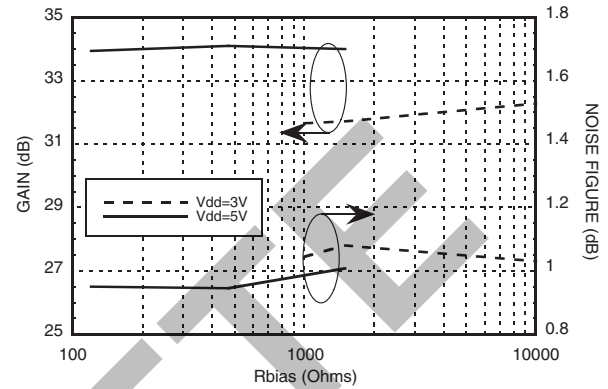
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AMPLIFIERS - LOW NOISE - SMT

Output IP3 vs. Rbias @ 1900 MHz



Gain, Noise Figure & Rbias @ 1900 MHz



OBSOLETE



Absolute Bias Resistor

Range & Recommended Bias Resistor Values for Idd

Vdd (V)	Rbias Ω			Idd1 (mA)	Idd2 (mA)
	Min	Max	Recommended		
3V	1K [1]	Open Circuit	1k	27	154
			1.5k	33	154
			10k	46	154
5V	0	Open Circuit	120	70	168
			470	88	168
			1.5k	104	168

[1] Operation with Vdd= 3V and Rbias < 1K Ohm may result in the part becoming conditionally stable which is not recommended.

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	5.5 V
RF Input Power (RFIN) (Vdd = +5 Vdc)	-5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 21.2 mW/°C above 85 °C)	1.9 W
Thermal Resistance (channel to ground paddle)	47.3 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd (Rbias = 1.5k)

Vdd (V)	Idd1 (mA)	Idd2 (mA)
2.7	22	150
3.0	33	154
3.3	44	155
4.5	87	163
5.0	104	168
5.5	121	169

Note: Amplifier will operate over full voltage ranges shown above.



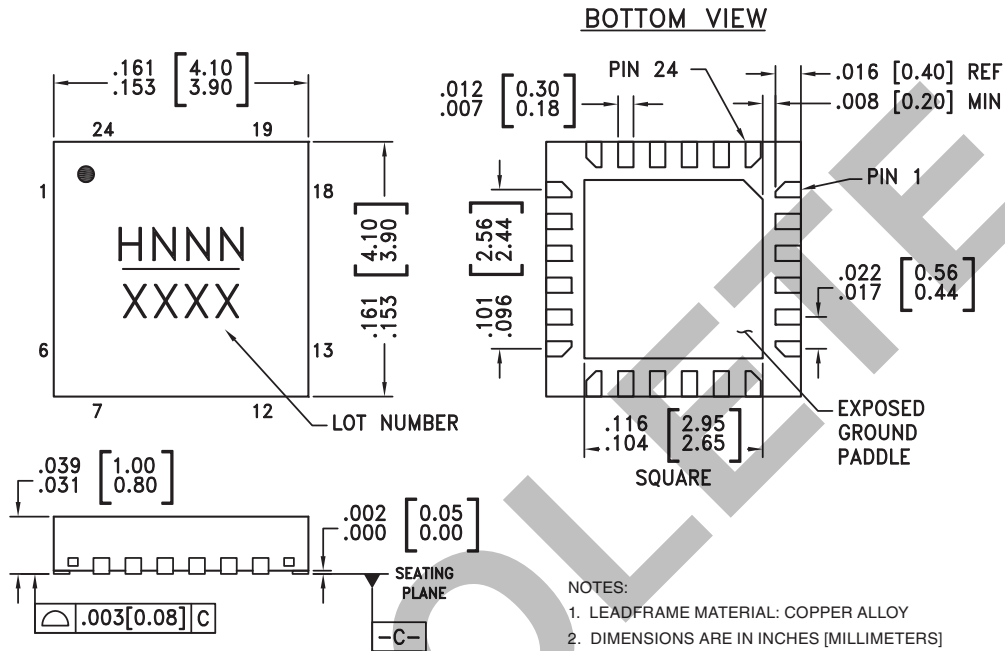
**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

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Outline Drawing



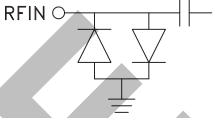
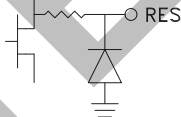
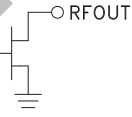
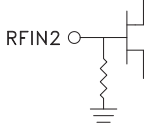
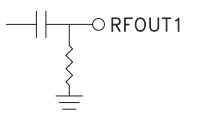
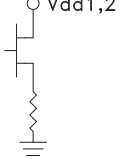
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC719LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H719 XXXX
HMC719LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H719 XXXX

[1] Max peak reflow temperature of 235 °C
 [2] Max peak reflow temperature of 260 °C
 [3] 4-Digit lot number XXXX



Pin Descriptions

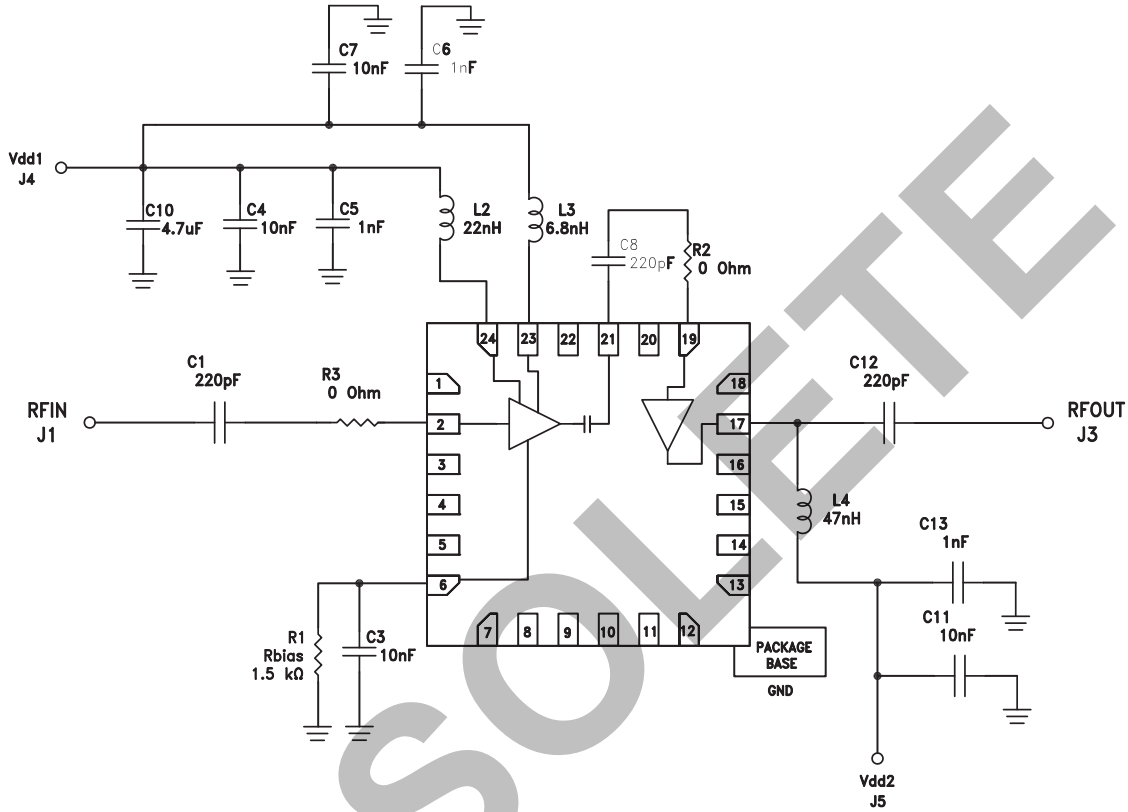
Pin Number	Function	Description	Interface Schematic
1, 3 - 5, 7 - 16, 18, 20, 22	N/C	No connection necessary. These pins may be connected to RF/DC ground without affecting performance.	
2	RFIN	This pin is DC coupled and matched to 50 Ohms.	
6	RES	This pin is used to set the DC current of the amplifier by selection of external bias resistor. See application circuit.	
17	RFOUT	RF Output and DC BIAS for the second amplifier. See Application Circuit for off-chip components.	
19	RFIN2	This pin is DC coupled. An off-chip DC blocking capacitor is required.	
21	RFOUT1	This pin is matched to 50 Ohms.	
23, 24	Vdd1, 2	Power Supply Voltage for the first amplifier. External bypass capacitors are required. See application circuit.	



**GaAs PHEMT MMIC HIGH IP3
LOW NOISE AMPLIFIER, 1.3 - 2.9 GHz**

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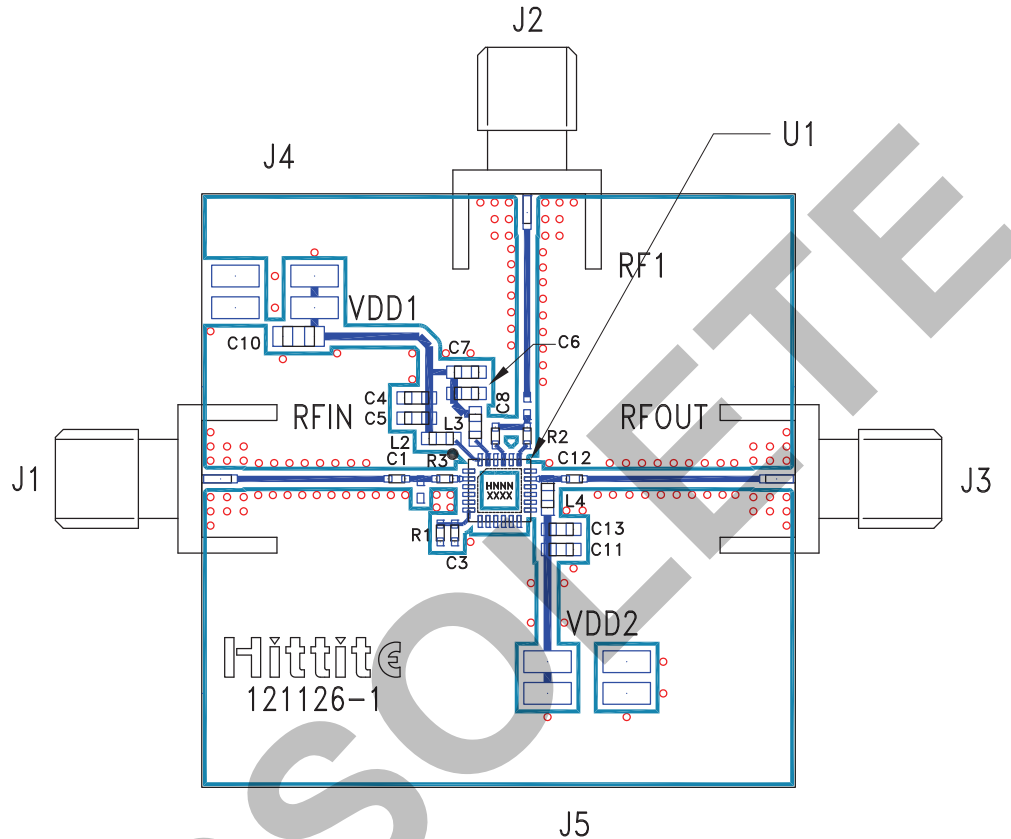
Application Circuit



AMPLIFIERS - LOW NOISE - SMT



Evaluation PCB



List of Materials for Evaluation PCB 121242 [1]

Item	Description
J1 - J3	PCB Mount SMA Connector
J4 - J5	2mm Vertical Molex Connector
C1, C8, C12	220 pF Capacitor, 0402 Pkg.
C3	10 nF Capacitor, 0402 Pkg.
C4, C7, C11	10 nF Capacitor, 0603 Pkg.
C5, C6, C13	1000 pF Capacitor, 0603 Pkg.
C10	4.7 uF Capacitor, 0805 Pkg.
L2	22 nH Inductor, 0402 Pkg.
L3	6.8 nH Inductor, 0603 Pkg.
L4	47 nH Inductor, 0603 Pkg.
R1	1.5 kOhm Rbias Resistor, 0402 Pkg.
R2, R3	0 Ohm Resistor, 0402 Pkg.
U1	HMC719LP4(E) Amplifier
PCB [2]	121126 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25RF

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.